

Near-IR and mid-IR subwavelength engineered Si photonics

C. Alonso-Ramos, D Pérez-Galacho, D Oser, X. Le Roux, D. Benedikovic, W. Zhang, S Serna, V Vakarin, E. Durán-Valdeiglesias, E. Cassan, et al.

▶ To cite this version:

C. Alonso-Ramos, D Pérez-Galacho, D Oser, X. Le Roux, D. Benedikovic, et al.. Near-IR and mid-IR subwavelength engineered Si photonics. Photonics North, Jun 2017, Ottawa, Canada. hal-01802112

HAL Id: hal-01802112 https://hal.science/hal-01802112v1

Submitted on 29 May 2018

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

Near-IR and mid-IR subwavelength engineered Si photonics

C. Alonso-Ramos*, D. Pérez-Galacho, D. Oser, X. Le Roux, D. Benedikovic, W. Zhang, S. Serna, V. Vakarin, E. Durán-Valdeiglesias, E. Cassan, D. Marris-Morini, L. Vivien

Centre de Nanosciences et de Nanotechnologies, CNRS, Université Paris-Sud, Université Paris-Saclay, C2N – Orsay, 91405 Orsay cedex, France. * carlos.ramos@u-psud.fr

Abstract— Periodically patterning Si with a pitch small enough to suppress diffraction, we synthesize an effective photonic medium with refractive index between those of Si and the cladding material. This technique releases new degrees of freedom in engineering of light-matter interaction, chromatic dispersion and light propagation in Si photonic waveguides. We present an overview of our recent results in the realization of novel devices including filters and waveguides for near- and mid-infrared wavelength range.

Keywords— Integrated optics devices; Waveguides, planar; Bragg reflector; Silicon.

The large transparency window of silicon (1.1 - 8 µm wavelength range) makes it a promising material for the implementation of a wide range of applications, including datacom, nonlinear and quantum optics, or sensing in the near-and mid-infrared wavelength ranges. Structuring silicon with features smaller than half of the wavelength releases new degrees of freedom to tailor material properties, allowing the realization of innovative high-performance Si devices [1].

Here, we exploit subwavelength nanostructuration to engineer light confinement, allowing the realization of two types of high-performance Si filters for quantum and sensing applications in the near- and mid-infrared. First, we will present subwavelength engineered Bragg filters that exploit an innovative differential corrugation width configuration to yield narrow-band rejection with a single etch step and relaxed fabrication constraints [2]. These filters exhibit remarkably narrow bandwidth of 1.1 nm with a rejection exceeding 40 dB. Then, we will present a corrugated Si membrane waveguide for single-mode operation in near- and mid-IR. Single-mode propagation in the mid-IR is allowed by choosing a 500-nmthick and 1100-nm-wide silicon waveguide. A novel waveguide corrugation approach radiates out the higher order modes in the near-IR, resulting in an effectively single-mode operation in near-IR.

This work was partially funded by the Agence Nationale de la Recherche (ANR-SITQOM-15-CE24-0005), the European Research Council (ERC) under the European Union's Horizon 2020 research and innovation program (ERC POPSTAR grant agreement No 647342) and the NANO2017 programme with STMicroelectronics funded by the "Ministère de l'économie, de l'industrie et du numérique", "Délégation Générales des Entreprises".

F. Mazeas, L. Labonte, S. Tanzilli Université Côte d'Azur, CNRS, Institut de Physique de Nice, Parc Valrose, 06108 Nice Cedex 2, France

P. Cheben

Information and Communications Technologies National Research Council Canada Ottawa, Canada

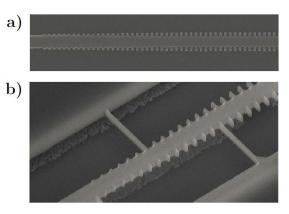


Fig. 1: Scanning electron microscope image of: (a) high pump-rejection filter for quantum photonics, and (b) Si membrane waveguide for applications in the near- and mid-infrared.

In conclusion, we exploit the subwavelength nanostructuration of Si to demonstrate efficient waveguide Bragg grating filters for several applications. Our achievements open a new route for the implementation of high-performance on-chip devices tailoring the flow of light in nanostructured silicon photonic waveguides.

REFERENCES

- [1] R. Halir, P. Bock, P. Cheben, A. Ortega-Moñux, C. Alonso-Ramos, J. H. Schmid, J. Lapointe, D.-X. Xu, J. G. Wangüemert-Pérez, I. Molina-Fernández, S. Janz, "Waveguide sub-wavelength structures: principles and applications," Laser & Photon. Rev. 9(1), L25 (2014).
- [2] D. Pérez-Galacho, C. Alonso-Ramos, F. Mazeas, X. Le Roux, D. Oser, W. Zhang, L. Labonté, S. Tanzilli, E. Cassan, D. Marriz-Morini, L. Vivien, "Optical pumprejection filter based on silicon sub-wavelength engineered photonic structures," Opt. Lett. 42(8), 1468 (2017).